

EVERFUSE

TM

Polymeric PTC Fuse

Product: SMD1812P200TF Revision: D Date: April 10, 2008 Page: 1 of 1

Device Specification



ELECTRICAL CHARACTERISTICS

						Maximum Time To Trip		Resistance	
Part Number	I _{hold} (A)	I _{trip} (A)	V _{max} (Vdc)	I _{max} (A)	$P_d^{max.}$ (W)	Current (A)	Time (Sec.)	$\begin{array}{c} \mathbf{R}_{\min} \\ (\Omega) \end{array}$	R_{1max} (Ω)
SMD1812P200TF	2.00	3.50	8	100	0.8	8.00	2.00	0.020	0.060

Note: I_{hold} = Hold current: maximum current device will pass without tripping in 20°C still air.

I $_{trip}$ = Trip current: minimum current at which the device will trip in 20 $^\circ\!\mathrm{C}$ still air.

 V_{max} = Maximum voltage device can withstand without damage at rated current (I max)

 I_{max} = Maximum fault current device can withstand without damage at rated voltage (V_{max})

 P_d = Power dissipated from device when in the tripped state at 20°C still air.

R _{min}= Minimum resistance of device in initial (un-soldered) state.

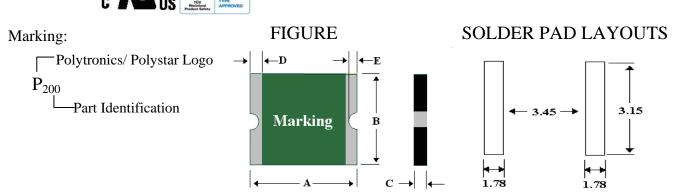
R $_{1max}$ = Maximum resistance of device at 20°C measured one hour after tripping or reflow soldering of 260°C for 20 sec.

*Value specified were determined using the PCB with 0.030"*1.5oz copper traces.

*Customer should verify the device performance in their specified conditions.

Caution: Operation beyond the specified rating may result in damage and possible arcing and flame.





Note: Polystar is Polytronics's manufacturing site in China. The Polystar ID marking shall appear on smallest package.

PHYSICAL DIMENSIONS (mm)

Part Number	А		В		С		D		Е	
	Min.	Max.								
SMD1812P200TF	4.37	4.73	3.07	3.41	0.81	1.20	0.30	1.20	0.25	0.50

◎ Specifications are subject to change without notice.